

Atomic Structure and Spectroscopy of Single Metal (Cr, V) Substitutional Dopants in Monolayer MoS₂

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Supporting Information

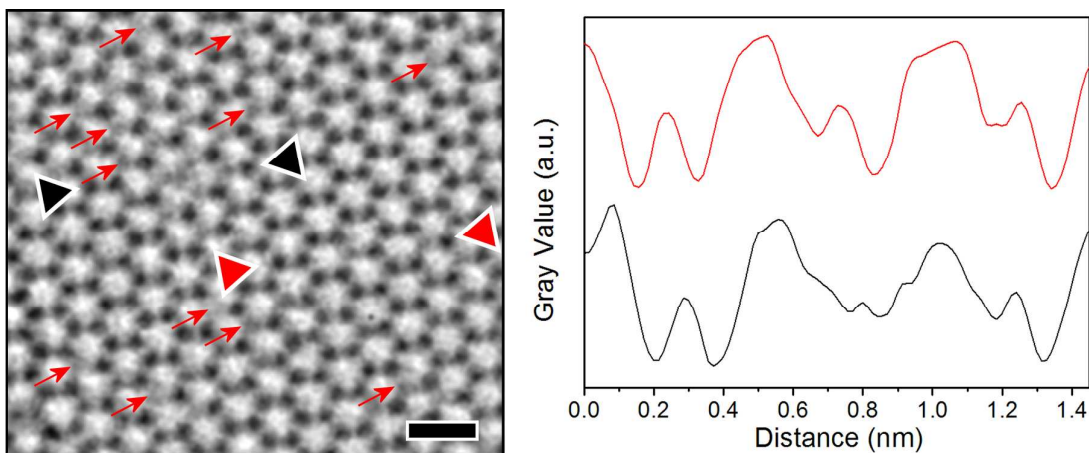


Figure S1. AC-TEM image of monolayer CVD MoS₂ with intensity line profiles taken from the respectively colored pointers. Profiles are of an S@Mo or Cr@Mo (black line profile), and two

adjacent S vacancies for reference (red line profile). Red arrows indicate some other S vacancy sites.

Scale bar 0.5 nm.